

## **NCE N-Channel Super Trench Power MOSFET**

### **Description**

The NCEP0218G uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

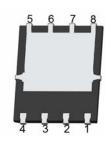
#### **General Features**

- $V_{DS}$  =200V, $I_D$  =18A  $R_{DS(ON)}$ =70m $\Omega$  (typical) @  $V_{GS}$ =10V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 150 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!

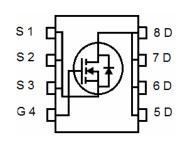
#### **DFN 5X6**





**Top View** 

**Bottom View** 



**Schematic Diagram** 

### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P0218G	NCEP0218G	DFN5X6-8L	_	-	-

#### Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	200	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	18	А
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	12.6	Α
Pulsed Drain Current	I <sub>DM</sub>	72	Α
Maximum Power Dissipation	P <sub>D</sub>	105	W
Derating factor		0.84	<b>W</b> /℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	180	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	$^{\circ}$ C

#### **Thermal Characteristic**

Thermal Résistance, Junction-to-Case <sup>(Note 2)</sup> ReJC  1.2
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# Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			•
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	200	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =200V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)			•			•
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_D=250\mu A$	2.5	3.5	4.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =18A	-	70	80	mΩ
Forward Transconductance	<b>g</b> FS	$V_{DS}$ =5 $V$ , $I_D$ =18 $A$	15	-	-	S
Dynamic Characteristics (Note4)			•			•
Input Capacitance	C <sub>lss</sub>		-	951		PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V,	-	82		PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	2		PF
Switching Characteristics (Note 4)			•			•
Turn-on Delay Time	t <sub>d(on)</sub>		-	6	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =100V, RL=5.5 $\Omega$	-	7	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =3 $\Omega$	-	15	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	4	-	nS
Total Gate Charge	Qg	V <sub>DS</sub> =100V,I <sub>D</sub> =18A,	-	18	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	7.5	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	4.6	-	nC
Drain-Source Diode Characteristics			•			•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =18A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	18	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25$ °C, $I_F = I_S$	-	30	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	125	-	nC

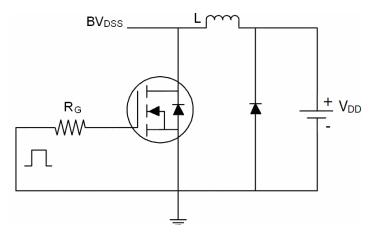
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,V  $_{DD}$  =50 V,V  $_{G}$  =10 V,L=0.5 mH,Rg=25  $\Omega$

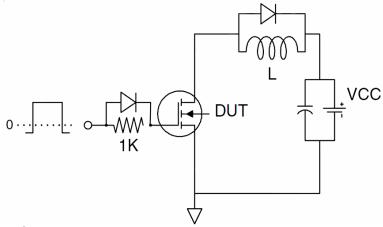


### **Test Circuit**

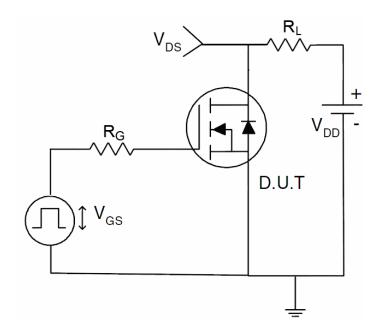
# 1) E<sub>AS</sub> test Circuit



### 2) Gate charge test Circuit

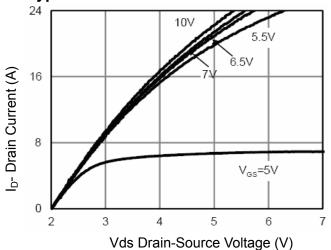


## 3) Switch Time Test Circuit

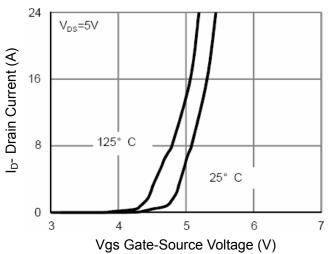




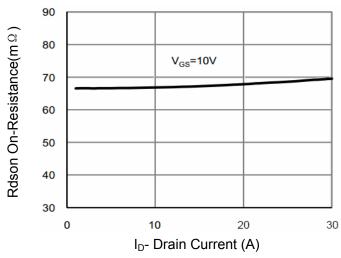




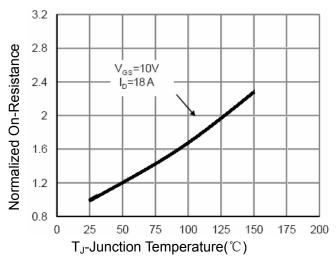
**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 



**Figure 3 Rdson- Drain Current** 



**Figure 4 Rdson-Junction Temperature** 

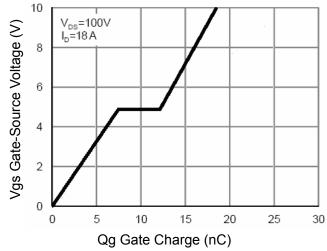


Figure 5 Gate Charge

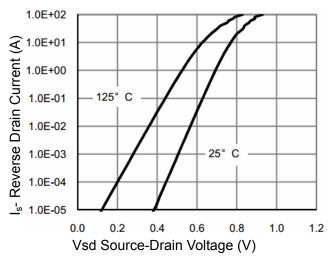
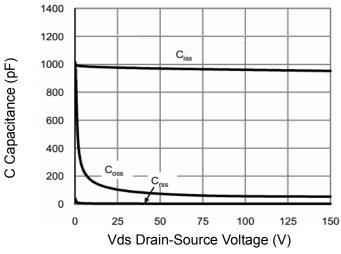


Figure 6 Source- Drain Diode Forward





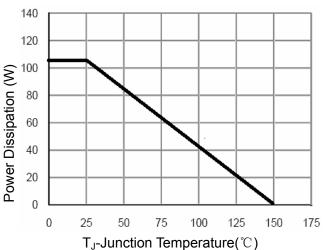
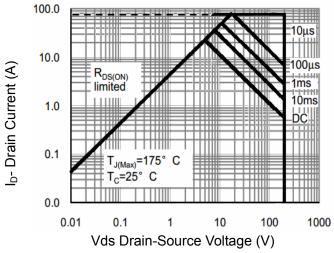
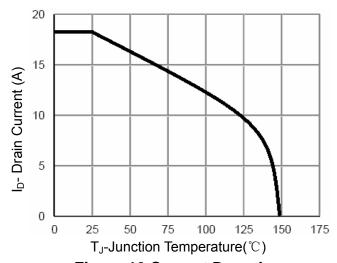


Figure 7 Capacitance vs Vds

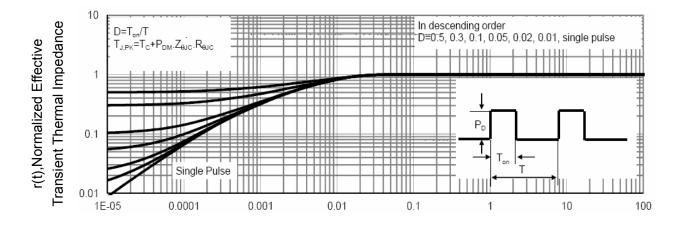
Figure 9 Power De-rating



**Figure 8 Safe Operation Area** 



**Figure 10 Current De-rating** 

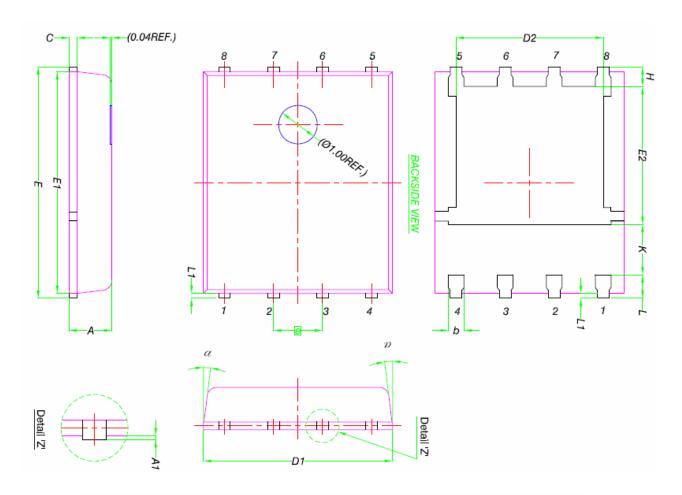


Square Wave Pluse Duration(sec)

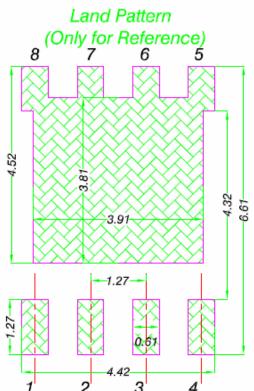
**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **DFN5X6-8L Package Information**



544	MILLIMETERS				
DIM.	MIN.	NOM.	MAX.		
Α	0.90	1.00	1.10		
A1	0	-	0.05		
b	0.33	0.41	0.51		
С	0.20	0.25	0.30		
D1	4.80	4.90	5.00		
D2	3.61	3.81	3.96		
Ε	5.90	6.00	6.10		
E1	5.70	5.75	5.80		
E2	3.38	3.58	3.78		
е		1.27 BSC			
Н	0.41	0.51	0.61		
K	1.10	-	-		
L	0.51	0.61	0.71		
L1	0.06	0.13	0.20		
α	<i>0</i> °	-	12°		





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